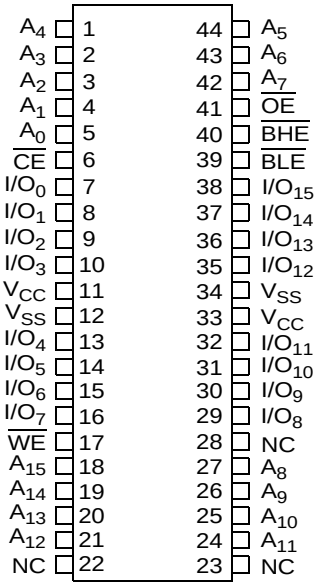
Selection Guide

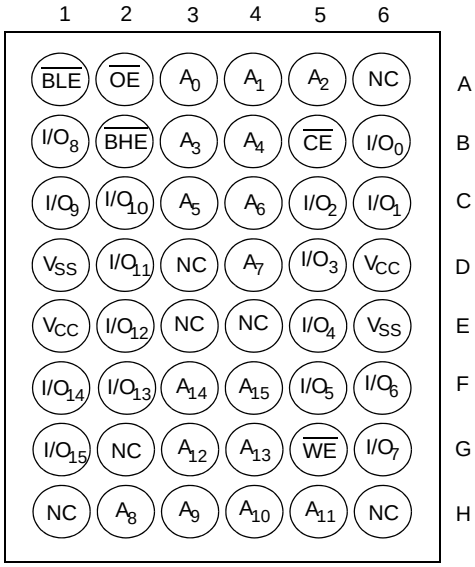
	–10 (Industrial/Automotive-A)	Unit
Maximum access time	10	ns
Maximum operating current	60	mA
Maximum CMOS standby current	3	mA

Pin Configuration[1]

SOJ/TSOP II
Top View



48-ball VFBGA
Top View



Notes
1. NC pins are not connected on the die.

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage temperature ..... –65 °C to +150 °C

Ambient temperature with power applied ..... –55 °C to +125 °C

Supply voltage on V_{CC} to Relative GND[2] ...–0.3 V to +4.6 V

DC Voltage applied to outputs in high-Z State[2] ..... –0.3 V to V_{CC}+0.3 V

DC input voltage[2] ..... –0.3 V to V_{CC}+0.3 V

Current into outputs (LOW) ..... 20 mA

Static discharge voltage..... > 2001 V (per MIL-STD-883, method 3015)

Latch-up current ..... >200 mA

Operating Range

Range	Ambient Temperature	V_{CC}	Speed
Industrial	–40 °C to +85°C	3.3 V ± 0.3 V	10 ns
Automotive-A	–40 °C to +85°C		10 ns

DC Electrical Characteristics Over the Operating Range

Parameter	Description	Test Conditions		–10 (Ind'l/Auto-A)		Unit
				Min.	Max.	
V_{OH}	Output HIGH voltage	V_{CC} = Min., I_{OH} = –4.0 mA		2.4		V
V_{OL}	Output LOW voltage	V_{CC} = Min., I_{OL} = 8.0 mA			0.4	V
V_{IH}	Input HIGH voltage			2.0	V_{CC} + 0.3	V
V_{IL}	Input LOW voltage[2]			–0.3	0.8	V
I_{IX}	Input leakage current	GND ≤ V_I ≤ V_{CC}		–1	+1	µA
I_{OZ}	Output leakage current	GND ≤ V_I ≤ V_{CC}, Output Disabled		–1	+1	µA
I_{CC}	V_{CC} operating supply current	V_{CC} = Max., I_{OUT} = 0 mA, f = f_{MAX} = $1/t_{RC}$	100 MHz		60	mA
			83 MHz		55	mA
			66 MHz		45	mA
			40 MHz		30	mA
I_{SB1}	Automatic CE Power-Down Current —TTL Inputs	Max. V_{CC}, $\overline{CE}$ ≥ V_{IH} V_{IN} ≥ V_{IH} or V_{IN} ≤ V_{IL}, f = f_{MAX}			10	mA
I_{SB2}	Automatic CE Power-Down Current —CMOS Inputs	Max. V_{CC}, $\overline{CE}$ ≥ V_{CC} – 0.3 V, V_{IN} ≥ V_{CC} – 0.3 V or V_{IN} ≤ 0.3 V, f = 0			3	mA

Capacitance[3]

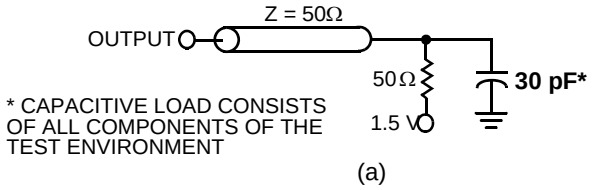
Parameter	Description	Test Conditions	Max.	Unit
C_{IN}	Input capacitance	T_A = 25°C, f = 1 MHz, V_{CC} = 3.3 V	8	pF
C_{OUT}	Output capacitance		8	pF

Thermal Resistance[3]

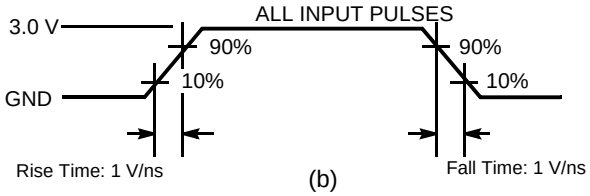
Parameter	Description	Test Conditions	SOJ	TSOP II	VFBGA	Unit
Θ_{JA}	Thermal resistance (Junction to Ambient)	Still Air, soldered on a 3 × 4.5 inch, four-layer printed circuit board	59.52	53.91	36	°C/W
Θ_{JC}	Thermal resistance (Junction to Case)		36.75	21.24	9	°C/W

Notes
2. V_{IL} (min.) = –2.0 V and V_{IH}(max) = V_{CC} + 1 V for pulse durations of less than 5 ns.
3. Tested initially and after any design or process changes that may affect these parameters.

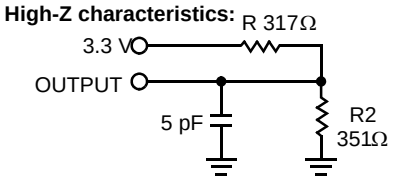
AC Test Loads and Waveforms[4]



(a)



(b)



(c)

Note

4. AC characteristics (except High-Z) are tested using the load conditions shown in Figure (a). High-Z characteristics are tested for all speeds using the test load shown in Figure (c).

Switching Characteristics Over the Operating Range[5]

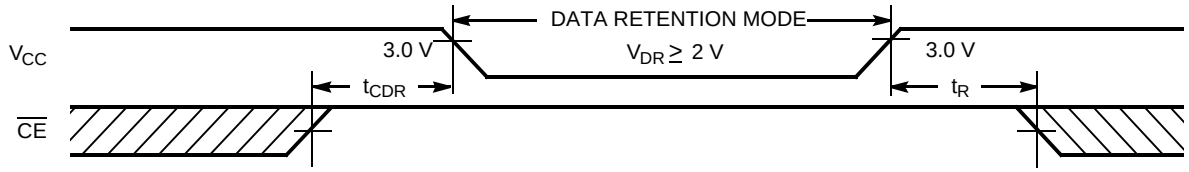
Parameter	Description	-10 (Ind'l/Auto-A)		Unit
		Min.	Max.	
Read Cycle				
t_{power}[6]	V_{CC}(typical) to the first access	100		µs
t_{RC}	Read cycle time	10		ns
t_{AA}	Address to data valid		10	ns
t_{OHA}	Data hold from address change	3		ns
t_{ACE}	$\overline{CE}$ LOW to data valid		10	ns
t_{DOE}	$\overline{OE}$ LOW to data valid		5	ns
t_{LZOE}	$\overline{OE}$ LOW to low-Z[8]	0		ns
t_{HZOE}	$\overline{OE}$ HIGH to high-Z[7, 8]		5	ns
t_{LZCE}	$\overline{CE}$ LOW to low-Z[8]	3		ns
t_{HZCE}	$\overline{CE}$ HIGH to high-Z[7, 8]		5	ns
t_{PU}[9]	$\overline{CE}$ LOW to power-up	0		ns
t_{PD}[9]	$\overline{CE}$ HIGH to power-down		10	ns
t_{DBE}	Byte Enable to data valid		5	ns
t_{LZBE}	Byte Enable to low-Z	0		ns
t_{HZBE}	Byte Disable to high-Z		6	ns
Write Cycle[10]				
t_{WC}	Write cycle time	10		ns
t_{SCE}	$\overline{CE}$ LOW to write end	8		ns
t_{AW}	Address set-up to write end	8		ns
t_{HA}	Address hold from write end	0		ns
t_{SA}	Address set-up to write start	0		ns
t_{PWE}	$\overline{WE}$ pulse width	7		ns
t_{SD}	Data set-up to write end	5		ns
t_{HD}	Data hold from write end	0		ns
t_{LZWE}	$\overline{WE}$ HIGH to low-Z[8]	3		ns
t_{HZWE}	$\overline{WE}$ LOW to high-Z[7, 8]		5	ns
t_{BW}	Byte enable to end of write	7		ns

Notes
5. Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5 V, input pulse levels of 0 to 3.0 V.
6. t_{POWER} gives the minimum amount of time that the power supply should be at typical V_{CC} values until the first memory access can be performed.
7. t_{HZOE}, t_{HZBE}, t_{HZCE}, and t_{HZWE} are specified with a load capacitance of 5 pF as in (c) of AC Test Loads. Transition is measured when the outputs enter a high impedance state.
8. At any given temperature and voltage condition, t_{HZCE} is less than t_{LZCE}, t_{HZOE} is less than t_{LZOE}, and t_{HZWE} is less than t_{LZWE} for any given device.
9. This parameter is guaranteed by design and is not tested.
10. The internal Write time of the memory is defined by the overlap of $\overline{CE}$ LOW, $\overline{WE}$ LOW and $\overline{BHE}$/$\overline{BLE}$ LOW. $\overline{CE}$, $\overline{WE}$ and $\overline{BHE}$/$\overline{BLE}$ must be LOW to initiate a Write and the transition of these signals can terminate the Write. The input data set-up and hold timing should be referenced to the leading edge of the signal that terminates the Write.

Data Retention Characteristics Over the Operating Range

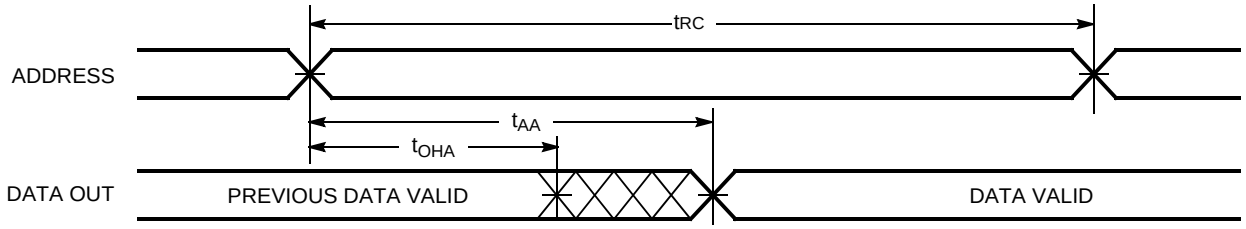
Parameter	Description	Conditions		Min.	Max.	Unit
V_{DR}	V_{CC} for data retention			2		V
I_{CCDR}	Data retention current	$V_{CC} = V_{DR} = 2.0$ V, $\overline{CE} \geq V_{CC} - 0.3$ V, $V_{IN} \geq V_{CC} - 0.3$ V or $V_{IN} \leq 0.3$ V	Industrial		3	mA
t_{CDR}[3]	Chip deselect to data retention time			0		ns
t_R[11]	Operation recovery time			t_{RC}		ns

Data Retention Waveform

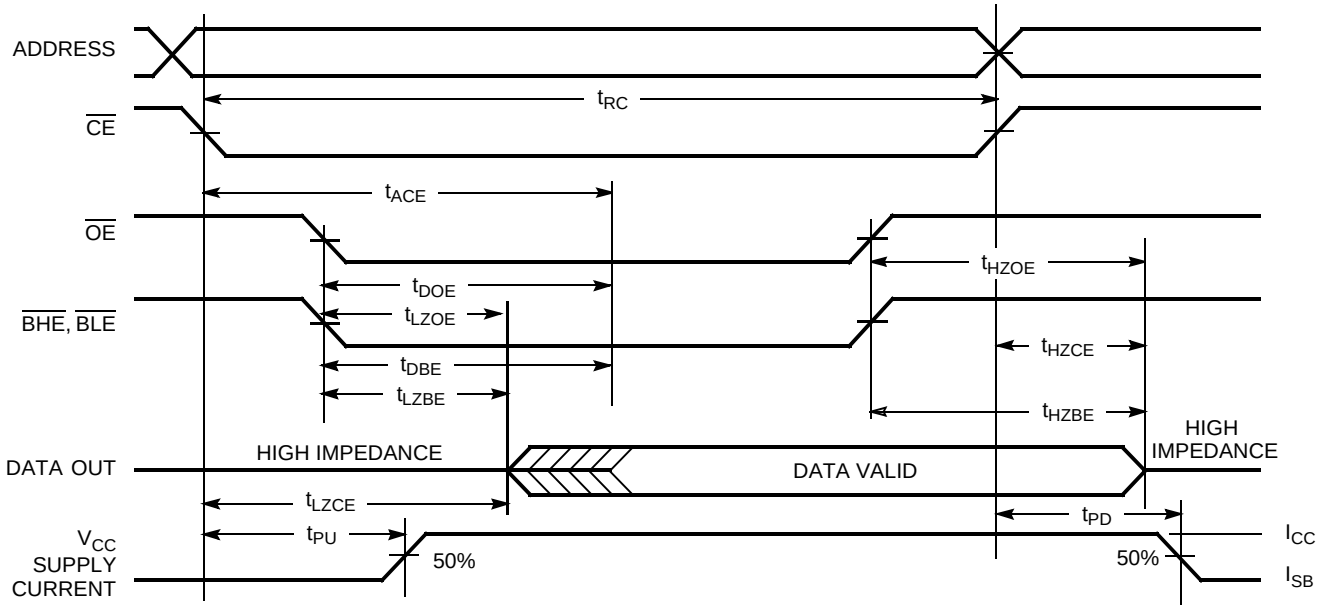


Switching Waveforms

Read Cycle No. 1 (Address Transition Controlled)[12, 13]



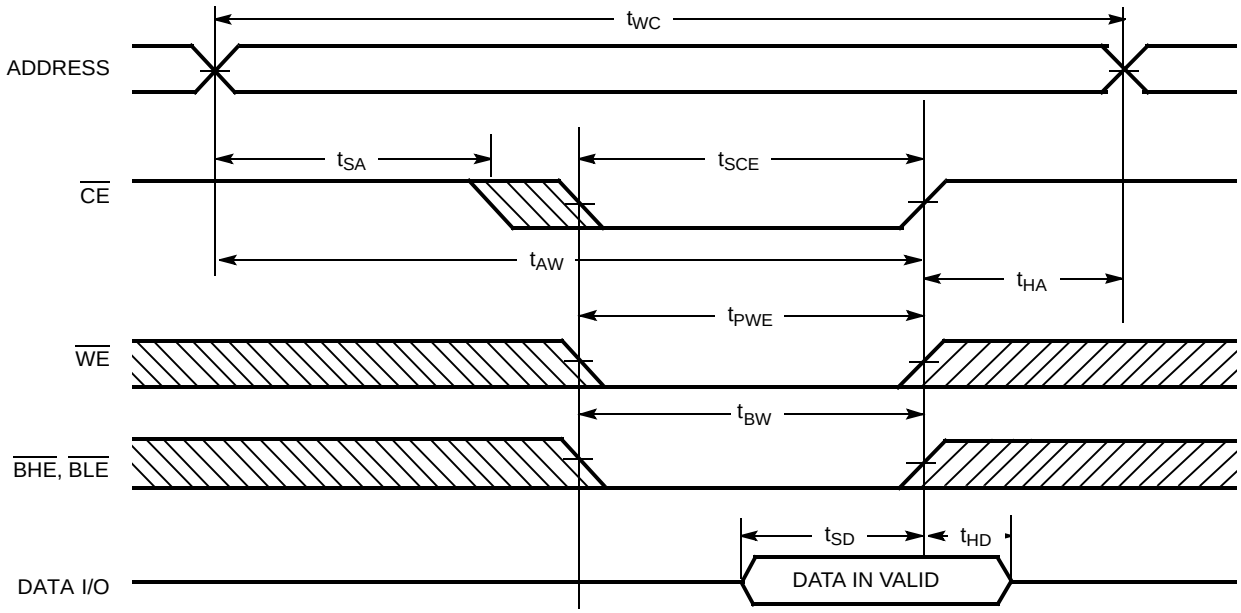
Read Cycle No. 2 ($\overline{OE}$ Controlled)[13, 14]



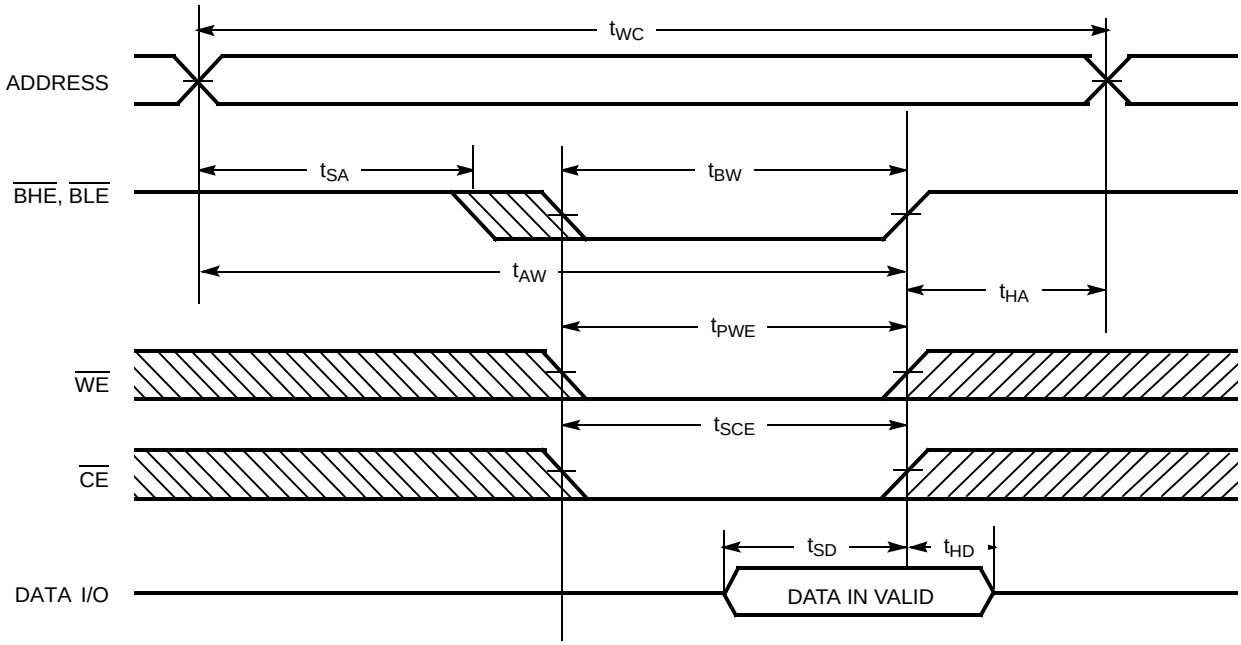
Notes
11. Full device operation requires linear V_{CC} ramp from V_{DR} to $V_{CC(min.)} \geq 50$ µs or stable at $V_{CC(min.)} \geq 50$ µs.
12. Device is continuously selected. $\overline{OE}$, $\overline{CE}$, $\overline{BHE}$ and/or $\overline{BLE} = V_{IL}$.
13. $\overline{WE}$ is HIGH for Read cycle.
14. Address valid prior to or coincident with $\overline{CE}$ transition LOW.

Switching Waveforms (continued)

Write Cycle No. 1 (CE Controlled)[15, 16]



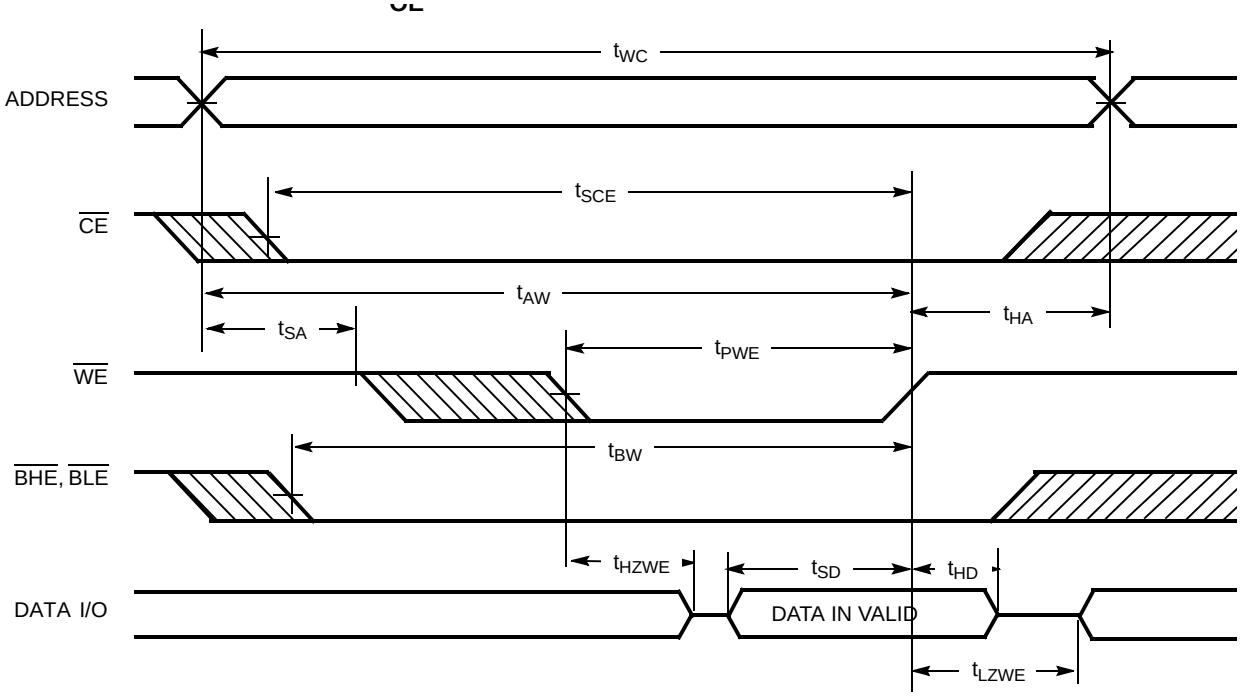
Write Cycle No. 2 (BLE or BHE Controlled)



Notes
15. Data I/O is high impedance if OE or BHE and/or BLE = V_{IH}.
16. If CE goes HIGH simultaneously with WE going HIGH, the output remains in a high-impedance state.

Switching Waveforms (continued)

Write Cycle No. 3 ($\overline{WE}$ Controlled, $\overline{OE}$ LOW)



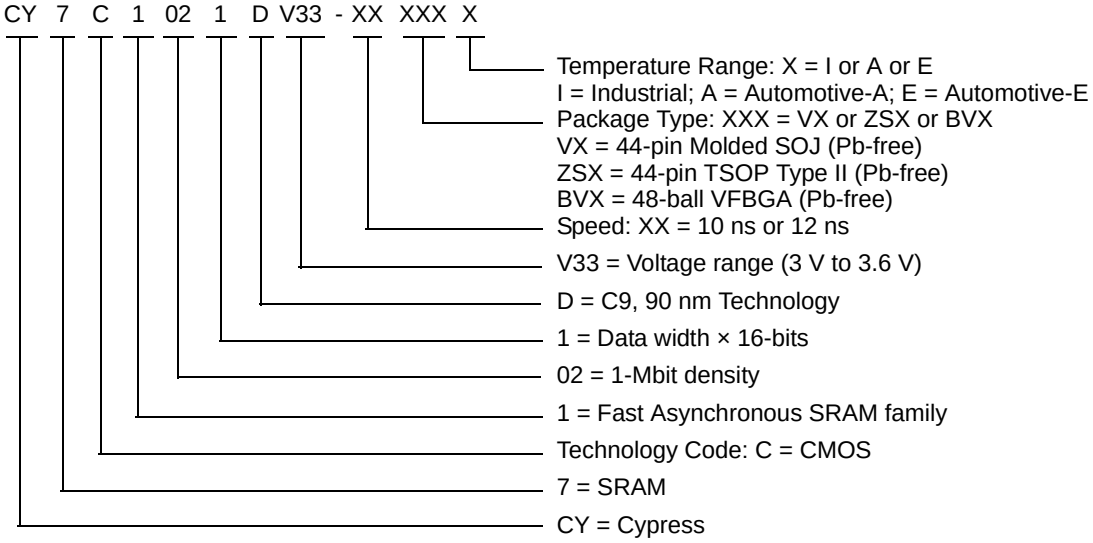
Truth Table

$\overline{CE}$	$\overline{OE}$	$\overline{WE}$	$\overline{BLE}$	$\overline{BHE}$	I/O_0–I/O_7	I/O_8–I/O_{15}	Mode	Power
H	X	X	X	X	High-Z	High-Z	Power-down	Standby (I_{SB})
L	L	H	L	L	Data Out	Data Out	Read – All bits	Active (I_{CC})
			L	H	Data Out	High-Z	Read – Lower bits only	Active (I_{CC})
			H	L	High-Z	Data Out	Read – Upper bits only	Active (I_{CC})
L	X	L	L	L	Data In	Data In	Write – All bits	Active (I_{CC})
			L	H	Data In	High-Z	Write – Lower bits only	Active (I_{CC})
			H	L	High-Z	Data In	Write – Upper bits only	Active (I_{CC})
L	H	H	X	X	High-Z	High-Z	Selected, outputs disabled	Active (I_{CC})
L	X	X	H	H	High-Z	High-Z	Selected, outputs disabled	Active (I_{CC})

Ordering Information

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
10	CY7C1021DV33-10VXI	51-85082	44-pin (400-Mil) Molded SOJ (Pb-free)	Industrial
	CY7C1021DV33-10ZSXI	51-85087	44-pin TSOP Type II (Pb-free)	
	CY7C1021DV33-10BVXI	51-85150	48-ball VFBGA (Pb-free)	
10	CY7C1021DV33-10ZSXA	51-85087	44-pin TSOP Type II (Pb-free)	Automotive-A

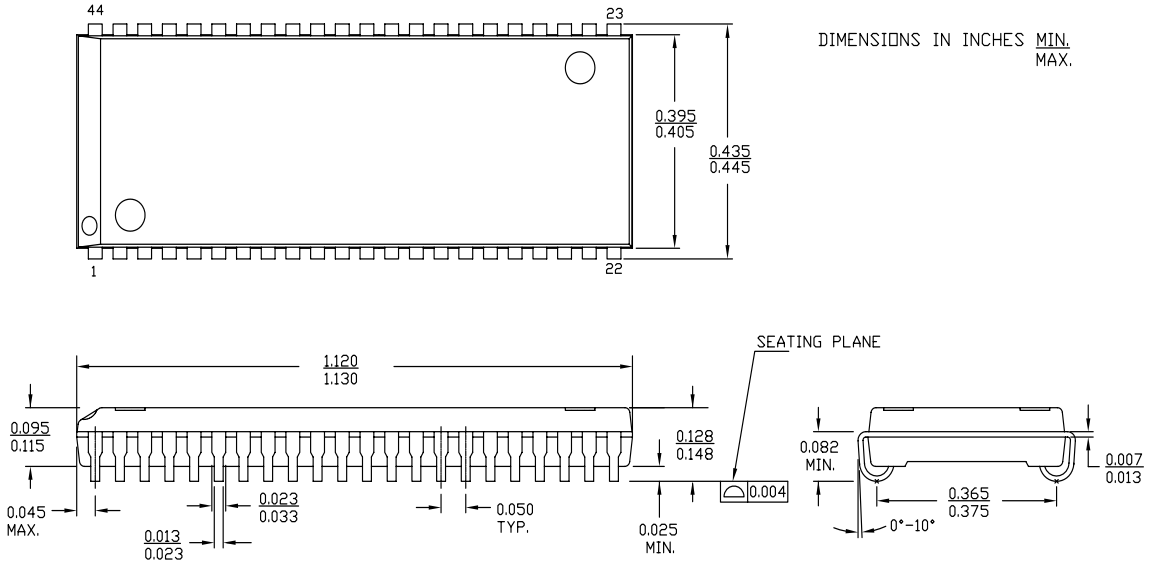
Ordering Code Definitions



Please contact your local Cypress sales representative for availability of these parts.

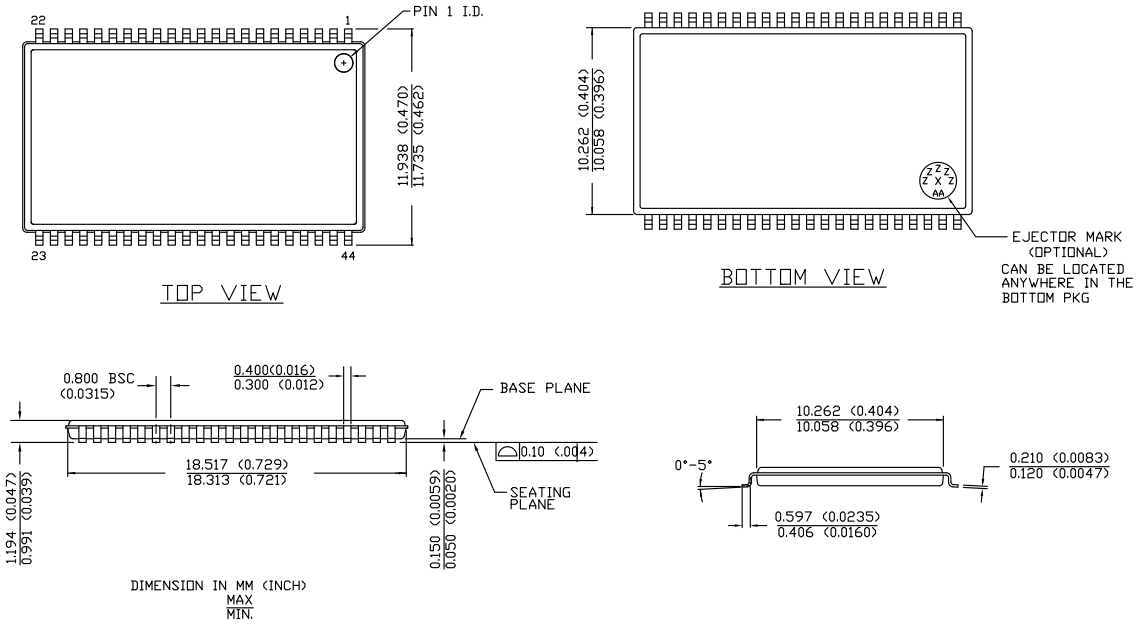
Package Diagrams

Figure 1. 44-pin (400-Mil) Molded SOJ (51-85082)



51-85082 *D

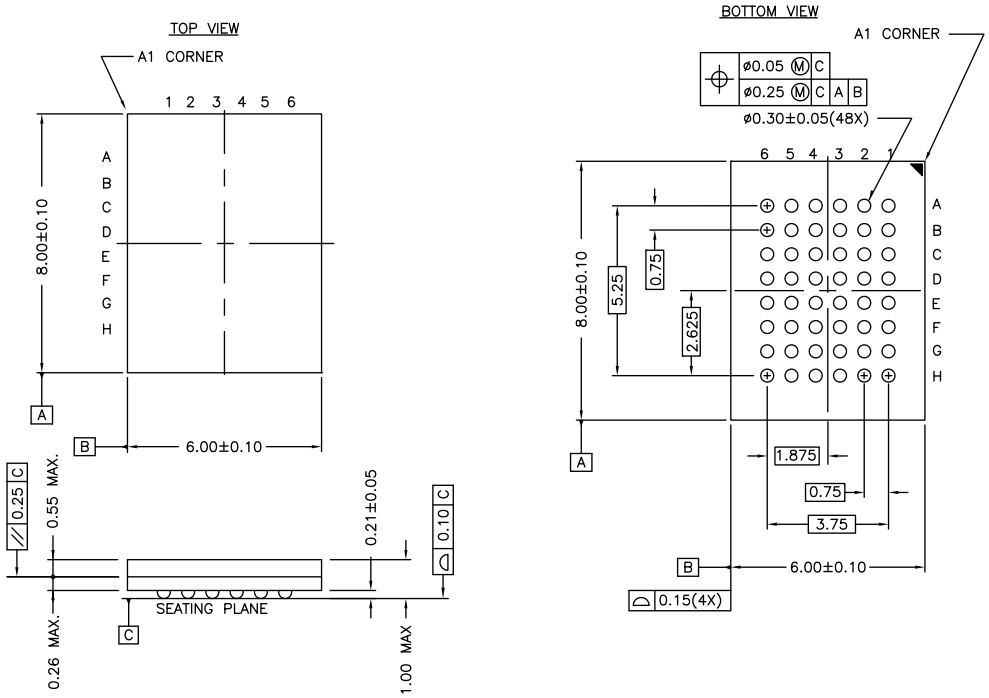
Figure 2. 44-pin Thin Small Outline Package Type II (51-85087)



51-85087 *D

Package Diagrams (continued)

Figure 3. 48-ball VFBGA (6 x 8 x 1 mm) (51-85150)



51-85150 *G

Document History Page

Document Title: CY7C1021DV33, 1-Mbit (64K x 16) Static RAM Document Number: 38-05460				
REV.	**ECN NO.**	**Issue Date**	**Orig. of Change**	**Description of Change**
**	201560	See ECN	SWI	Advance Information data sheet for C9 IPP
*A	233693	See ECN	RKF	DC parameters are modified as per Eros (Spec # 01-02165). Pb-free Offering In Ordering Information
*B	263769	See ECN	RKF	Changed $I/O_1 – I/O_{16}$ to $I/O_0 – I/O_{15}$ Added Data Retention Characteristics table Added T_{power} Spec in Switching Characteristics table Shaded Ordering Information
*C	307601	See ECN	RKF	Reduced Speed bins to –8 and –10 ns
*D	520652	See ECN	VKN	Converted from Preliminary to Final Removed Commercial Operating range Removed 8 ns speed bin Added I_{CC} values for the frequencies 83MHz, 66MHz and 40MHz Added Automotive Information Updated Thermal Resistance table Updated Ordering Information Table Changed Overshoot spec from V_{CC}+2 V to V_{CC}+1 V in footnote #4
*E	2898399	03/24/2010	AJU	Updated Package Diagrams
*F	3109897	12/14/2010	AJU	Added Ordering Code Definitions. Updated Package Diagrams.
*G	3421856	10/25/2011	TAVA	Template Update Updated Features, Selection Guide, Operating Range, DC Electrical Characteristics Over the Operating Range, Switching Characteristics Over the Operating Range[5], Data Retention Characteristics Over the Operating Range, Switching Waveforms, and Ordering Information Updated Package Diagrams

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